

CHONGQING CLOUDCHILD TECHNOLOGY CO., LTD

TO-263-2L Plastic-Encapsulate Diodes

CCDA40N10T Schottky Barrier Rectifier

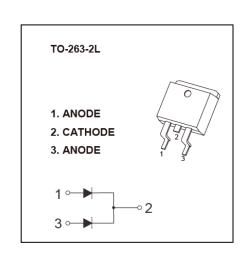
VRRM	VF(Type)	lo
100V	0.66V	40(2×20)A

DESCRIPTION

The CCDA40N10T uses trench technology. It can be used in a wide variety of applications.

Features

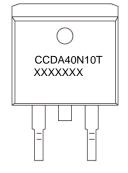
- Low Power Loss, High Efficiency
- Guard Ring Die Construction for Transient Protection
- High Current Capability and Low Forward Voltage Drop
- AEC-Q101 Qualified



Applications

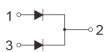
• Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting, especially for automotive load dump protection application.

MARKING



CCDA40N10T =Part No. XXXXXXX = Code

EQUIVALENT CIRCUIT



ABSOLUTE MAXIMUM RATINGS (T_c =25 $^{\circ}$ C unless otherwise noted)

Symbol	Parameter	Limit	Unit
V_{RRM}	Peak repetitive reverse voltage		
V_{RWM}	Working peak reverse voltage	100	V
V_R	DC blocking voltage		
V _{R(RMS)}	RMS reverse voltage	70	V
Io	Average rectified output current	40	А
I _{FSM}	Non-Repetitive peak forward surge current (8.3ms half sine wave)	250	А
P□	Power Dissipation	75	W
Rejc	Thermal resistance from junction to case ,Tc=25℃	2.0	°C/W
R _{⊝JA}	Thermal resistance from junction to ambient	62.5	°C/W
T _j , T _{stg}	Operating Junction and Storage Temperature Range	-55~+175	℃
-	Soldering Temperature , for 10S(1.6mm from case)	260	$^{\circ}$

ELECTRICAL CHARACTERISTICS

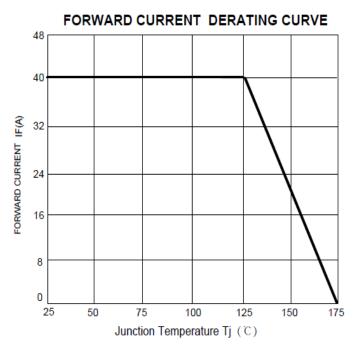
$T_c=25^{\circ}C$ unless otherwise specified

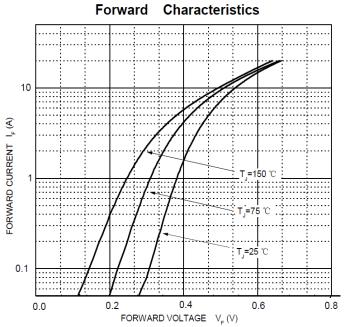
Parameter	Symbol	Test Condition	Min	Туре	Max	Unit
Maximum repetitive peak reverse voltage	VRRM	IR =1mA	100			V
		IF = 1A		0.36	0.47	V
Static Forward Voltage ¹	VF	IF = 10A		0.53	0.57	V
		IF =20A		0.66	0.74	V
Cathode-To-Anode Leakage Current ²	lR	VR =100V		18	50	μΑ
Operating and Storage Temperature Range	Тј,Тѕтс	-	55℃ to 17	75℃ Max		

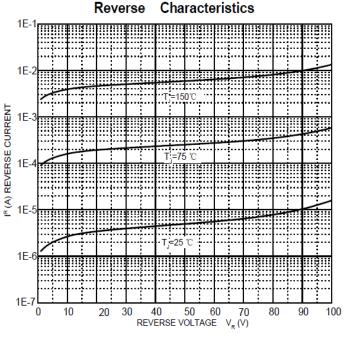
Notes:

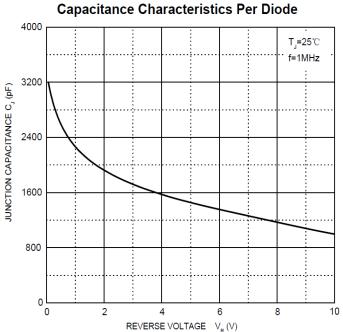
- 1. Electrical characteristics are reported for the bare die. Variations in customer packaging materials, dimensions and processes may affect parametric Performance.
- 2. Pulse width < 300 uS, Duty cycle < 2%.

Typical Characteristics

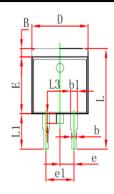


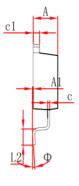


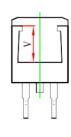




TO-263-2L Package Outline Dimensions

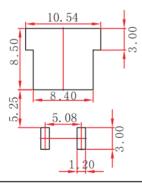






Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
Α	4.470	4.670	0.176	0.184	
A1	0.000	0.150	0.000	0.006	
В	1.120	1.420	0.044	0.056	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.310	0.530	0.012	0.021	
c1	1.170	1.370	0.046	0.054	
D	10.010	10.310	0.394	0.406	
E	8.500	8.900	0.335	0.350	
е	2.540 TYP.		0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
L	14.940	15.500	0.588	0.610	
L1	4.950	5.450	0.195	0.215	
L2	2.340	2.740	0.092	0.108	
L3	1.300	1.700	0.051	0.067	
Ф	0°	8°	0°	8°	
V	5.600 REF.		0.220	REF.	

TO-263-2L Suggested Pad Layout



Note:

- 1. Controlling dimension: in millimeters.
- 2. General tolerance:0.5mm.
- 3. The pad layout is for reference purposes only.

NOTICE

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Date of change	Rev#	revise content
2022/11/15	A/0	/